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Isc N-Channel MOSFET Transistor

TK20E60W

Ros(C • Enhand Vth =2. • 100% a • Minimu perform	ain-source on-resistance: DN) = 155mΩ (MAX) cement mode: .7 to 3.7V (V _{DS} = 10 V, I _D =1mA) avalanche tested im Lot-to-Lot variations for robust dev nance and reliable operation	Contraction of the second seco		
 DESCF Switchi 	ing Voltage Regulators			
• ABSOI	LUTE MAXIMUM RATINGS(Ta=25°C	1 the second sec		
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V _{GS}	Gate-Source Voltage	±30	V	
ID	Drain Current-Continuous	20	A	
Ідм	Drain Current-Single Pulsed	80	A	↑ mm
P _D	Total Dissipation @Tc=25°C	165	W	DIM MIN MAX A 15.50 15.90 B 9.80 10.20
Тј	Max. Operating Junction Temperature	150	°C	C 4.20 4.50 D 0.70 0.90 F 3.40 3.70
T _{stg}	Storage Temperature	-55~150	°C	G 4.98 5.18 H 2.68 2.90 J 0.44 0.60
• THERM	MAL CHARACTERISTICS	K 12.80 13.40 L 1.20 1.45 Q 2.70 2.90		
SYMBOL	PARAMETER	МАХ	UNIT	R 2.30 2.70 S 1.29 1.35
Rth(ch-c)	Channel-to-case thermal resistance	0.757	°C/W	U 6.45 6.65 V 8.66 8.86

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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	600			V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} = 10V; I _D =1mA	2.7		3.7	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =10A			155	mΩ
lgss	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} = 0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 600V; V _{GS} = 0V			100	μA
VSDF	Diode forward voltage	I _{DR} =20A, V _{GS} = 0 V			1.7	V



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